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The novel and facile preparation of multilayer MoS₂ crystals by a chelation-assisted sol–gel method and their electrochemical performance

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Multilayer molybdenum disulfide (MoS₂) was facilely prepared by a chelation-assisted sol–gel method with ammonium molybdate tetrahydrate ((NH₄)₆Mo₇O₂₄·4H₂O) as the molybdenum source, thioacetamide (CH₃CSNH₂) as the sulfur source and diethylenetriamine pentaacetic acid (Dtpa) as the chelating agent, subsequently followed by high-temperature calcination. The chelating agent Dtpa ingeniously mediated the chelation reaction of the system and promoted the formation of a monolithic gel. The hexagonal MoS₂ crystal (2H-MoS₂) with good crystallinity precipitated after calcination at 1000 °C with the Mo and S mass ratio of 1 : 3. The adjustable MoS₂ layers stacked together to form MoS₂ flakes, and these flakes aggregated to construct crystalline MoS₂ particles. The electrochemical tests showed the possibility of as-prepared MoS₂ crystals applied as a negative electrode for lithium ion batteries.

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1. Introduction

Molybdenum disulfide (MoS₂) is a type of layered compound with a graphene-like structure, and has been widely applied in electrochemical, optical and mechanical fields due to its special structure and excellent properties.^{1,2} Structurally, MoS₂ crystals are stacked by S atom layers and Mo atom layers arranged alternately where every Mo atom connects six S atoms with covalent bonds, and the adjacent layers interact by van der Waals force.^{3,4}

Up to now, a series of MoS₂ with different nanostructures such as nanosheets, nanoflowers, microspheres and monolayered MoS₂ sheets have been used in lithium ion battery storage due to the high reversible capacity (up to 1290 mA h g⁻¹). Ding *et al.* successfully prepared MoS₂ microspheres with good initial discharge and charge capacities (1160 and 791 mA h g⁻¹) and a capacity of 672 mA h g⁻¹ after 50 cycles.⁵ Lin *et al.* produced sulfur-depleted monolayered MoS₂ nanocrystals by exfoliating and disintegrating the bulk MoS₂ and the products showed excellent catalytic performance on HER.⁶ Chhowalla *et al.* demonstrated that metallic 1T phase MoS₂ nanosheets prepared by chemical exfoliation can intercalate ions such as H⁺, Li⁺ and Na⁺ efficiently and reach capacitance values from 400 to ~700 F cm⁻³.⁷ Hu *et al.* synthesized MoS₂ nanoflowers with expanded interlayers and used the products as Na-ion battery anode with high discharge capacities and good rate capability.⁸ Wang *et al.* prepared single-layer MoS₂/graphene composites as the anode electrode of lithium ion battery with

better cycle performance and rate capability than pure MoS₂ electrode due to the good electron conductivity of graphene and the synergy effect between MoS₂ and graphene.^{3,8}

There have been various synthetic methods to prepare MoS₂ and its composites, including hydrothermal synthesis, solid-state process, chemical vapor deposition (CVD), *etc.*^{9–11} Wherein, hydrothermal synthesis is a common method for the preparation of well-crystallized MoS₂ with various morphologies due to high temperature and pressure conditions.^{12,13} However those preparation methods almost are expensive, complicated and low productive. Sol–gel method is a new synthetic route for advanced materials based on low-temperature, high production, moderate reacting conditions and molecular-level mixture.¹⁴ So sol–gel method could be a cheap and simple way to prepare MoS₂ crystal. At present, only Li *et al.* reported the preparation of porous MoS₂ *via* a sol–gel route using (NH₄)₂Mo₃S₁₃ as precursor.¹⁵ However, the dissolving reaction of the precursor (NH₄)₂Mo₃S₁₃ to prepare “Mo₃S₁₂” gel is not supposed to be real sol–gel process. In addition, the precursor (NH₄)₂Mo₃S₁₃ is quite rare and very hard to synthesize. Therefore, it is essential to develop an effective and low-cost sol–gel approach to prepare MoS₂ materials.

In the present work we demonstrate a novel and facile chelation-assisted sol–gel method to prepare multilayer MoS₂. The common and inexpensive ammonium molybdate tetrahydrate ((NH₄)₆Mo₇O₂₄·4H₂O), thioacetamide (CH₃CSNH₂) and diethylenetriamine pentaacetic acid (Dtpa) were employed as molybdenum source, sulfur source and chelating agent, respectively. The mass ratio of Mo and S has an important role on the formation of multilayer MoS₂ crystalline phase. The synthesis mechanism, surface morphology, crystal structure and electrochemical performances of the as-prepared MoS₂ were also studied.

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2. Experimental

2.1. Preparation of MoS₂

All reagents are purchased from Aladdin Industrial Corporation and are AR (analytically pure) level. Three typical experiments were carried out and the corresponding samples were named as MoS₂-1, MoS₂-2 and MoS₂-3, which are different in the amount of S source. For the preparation of MoS₂-1, 0.2 g (0.16 mmol) ammonium molybdate tetrahydrate ((NH₄)₆Mo₇O₂₄·4H₂O) was firstly dissolved in 8 mL deionized water, and then 0.4 g (5.32 mmol) thioacetamide (CH₃CSNH₂) was added into the solution under continuous stirring. 0.05 g diethylenetriamine pentaacetic acid (Dtpa) was added into the solution to obtain the brown sol under stirring for 1 h. The sol was transferred into 60 °C oven for 12 h to gelate into bronze gel and kept drying at 60 °C for two days. After drying, some of the xerogel was calcinated in the tube furnace at 1000 °C for 4 h in a stream of argon flowing at 180 sccm to form 2H-MoS₂ phase. MoS₂-2 and MoS₂-3 were synthesized in the same process with the amounts of CH₃CSNH₂ of 0.6 and 0.8 g respectively.

2.2. Characterization

The X-ray diffraction (XRD) patterns of the samples were carried out on an X'Pert Pro diffractometer with a Cu K α radiation ($\lambda = 0.15418$ nm). The step size is 0.02626°, the time per step is 25.5 s, and the total scan time is 4 min 42 s without any mask or filters. Raman spectra were performed on the Renishaw InVia Raman microscope under the excitation length of 532 nm. The morphologies and microstructures of the samples were observed by Hitachi S-4800 scanning electron microscopy (SEM) operating at 3.0 kV and JEOL 2100F transmission electron microscopy (TEM) at an acceleration voltage of 200 kV. Electrochemical measurements were performed using CR 2025 coin cells. The preparation process of SEM samples are as follows. At first, samples were dispersed homogeneously in ethyl alcohol with ultrasonic processing. Then the suspension liquid were dropped onto the aluminum foil. After the ethyl alcohol volatilized, the samples were left on the aluminum foil. The preparation process of TEM samples was the same as the SEM one except the objective table was copper grid. The working electrode was prepared by coating the slurry (80 wt% of active materials, 10 wt% of carbon black, and 10 wt% of polyvinylidene fluoride binder in *N*-methyl-2-pyrrolidinone) onto a Cu foil and dried in a vacuum oven at 120 °C for 12 h. A lithium foil was used as the counter electrode, a mixture of 1 M LiPF₆ in ethylene carbonate (EC)–dimethyl carbonate (DMC) (1 : 1 by volume) was employed as the electrolyte and a polypropylene microporous film was applied as the separator. Cell assembly was conducted in an argon-filled glovebox with oxygen and water concentration below 1 ppm. The galvanostatic charge/discharge measurements were carried out in a Land battery testing system in the voltage range of 0.001–3 V (vs. Li⁺/Li). The cyclic voltammetry (CV) tests were performed between 0.05 V and 3.0 V at a scan rate of 0.2 mV s⁻¹ on a CHI660C electrochemical workstation (Shanghai Chenhua, China). The electrochemical impedance spectroscopy (EIS) measurements

were tested on the same workstation with the frequency ranging from 0.01 Hz to 100 kHz.

3. Results and discussion

Fig. 1 shows the synthesis mechanism of multilayer MoS₂ by chelation-assisted sol-gel method with diethylenetriamine pentaacetic acid (Dtpa) as chelating agent. Firstly, amounts of [Mo₇O₂₄]⁶⁻ ionic groups existed in the neutral solution. [Mo₇O₂₄]⁶⁻ is composed of seven octahedral [MoO₆] ionic groups where three different bond lengths exist between Mo and O atoms.^{39,40} Then the S²⁻ ions provided by CH₃CSNH₂ substituted for the terminal O atoms combined by Mo–O ionic bond because the bond energy of Mo–S is higher than that of terminal Mo–O. After adding Dtpa into the solution, the chelating agent attacked some new S atoms, broke the Mo–S bonds, and chelated with Mo atoms which lacked electrons to form stable electron structure. In the process, some of the S source were lost in the form of H₂S. Every Dtpa molecule connected three Mo atoms of different Mo₇O₂₄⁶⁻ ionic groups to form a complicated network structure, which promoted the formation of gel. The wet gel gradually formed at 60 °C in 12 h. Then it transformed into xerogel in two days when the water was totally evaporated and the shrinkage happened in the range between 40% and 60% of the original size. The crystallization of the complex gel was conducted by calcinations at 1000 °C, and the multilayer MoS₂ can be facily obtained.

The XRD patterns of as-prepared samples show the precipitates are hexagonal 2H-MoS₂ (JCPDS 37-1492) with different crystallinity (Fig. 2). It is obvious that the MoS₂-2 sample displays the sharpest diffraction peaks, indicating the highest crystallinity. It reveals that complete MoS₂ crystal tends to be formed when the mass ratio of Mo source and S source is 1 : 3. The diffraction peak of MoS₂-2 sample at $2\theta = 14.2^\circ$ indicates the MoS₂ layers stack orderly along (002) direction with a *d*-spacing of 0.62 nm. The (100) reflection at $2\theta = 33.5^\circ$ and (110) reflection at $2\theta = 59.1^\circ$ can be found in MoS₂-3 sample but no clear (002) reflection. It is supposed that some complicated polysulfide molybdenum were synthesized owing to redundant

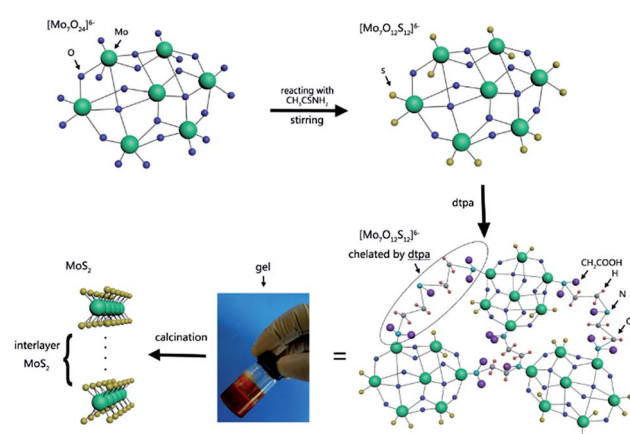


Fig. 1 Preparation process of MoS₂ by sol-gel method assisted by Dtpa.



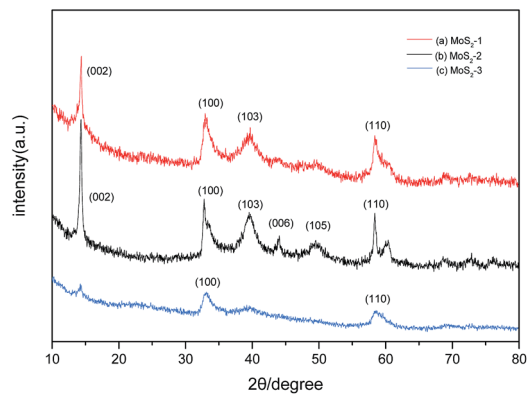


Fig. 2 XRD patterns of as-prepared samples.

S source in MoS₂-3 sample and few MoS₂ layers are stacked in the *c* direction.¹⁶ According to the Scherrer formula, $D = K\lambda / B \cos \theta$, $K = 0.89$, $\lambda = 0.154056$ nm, $\theta = 14.2^\circ$, $B = 0.507$ for MoS₂-2 and $B = 0.591$ for MoS₂-1. The average dimension of MoS₂ in *z*-axis is roughly estimated at about 15 nm in MoS₂-2 sample corresponding to 25 MoS₂ layers, which was facilitated by high-temperature calcination. For MoS₂-1 sample, the MoS₂ grain dimension in *z*-axis is about 13 nm, corresponding to 21 MoS₂ layers approximately. It shows that the mass ratio of Mo and S plays a role on the formation of multilayer MoS₂ to some extent.

The three samples were further investigated to analyze the inner structure by Raman spectroscopy (Fig. 3). It has been proved that E_{2g}¹ and A_{1g} peaks of monolayer MoS₂ appear at 384.3 and 403 cm⁻¹, respectively.¹⁷ With the increase of layer numbers, the in-plane E_{2g}¹ vibration weakens and the out-of-plane A_{1g} vibration strengthens. When the layer number is over 6, the E_{2g}¹ and A_{1g} peaks are observed at 382 and 408 cm⁻¹ stably.^{18,19} It is seen that the MoS₂-2 sample exhibits a strong out-of-plane vibration at 408 cm⁻¹ and a relatively weaker in-plane vibration at 382 cm⁻¹. However, the signal of this Raman spectroscopy is a little weak and red shifts are found in MoS₂-1 and MoS₂-3 samples. It is supposed that amorphous substances and defects in the resultant sample disorder the uniform MoS₂ molecule vibrations, thus causing these

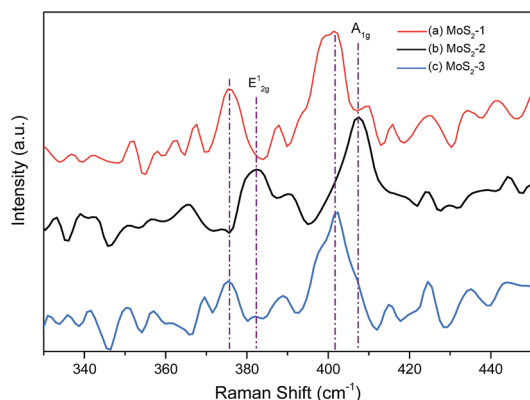


Fig. 3 Raman spectroscopy of as-prepared samples.

phenomena. Due to the selection rules for scattering geometry and limited rejection of the Raleigh scattered radiation, the other two vibration modes E_{1g} and E_{2g}² could not be detected.²⁰ It proves that the mass ratio of Mo and S also impacts the inner structure of as-prepared MoS₂.

The microstructures and morphologies of as-prepared MoS₂-2 sample were observed by SEM and TEM (Fig. 4). It is seen that the MoS₂ precipitates exist in the form of particles with the size of <2 μm and some agglomeration (Fig. 4a). Fig. 4b depicts irregular MoS₂ flakes aggregate together to form larger particles. As shown in Fig. 4c, the MoS₂ nanosheets stack together to form a large flake with different inside thickness. It is clearly observed from Fig. 4d that a nanosheet has some parallel MoS₂ crystal fringes with an interlayer distance of 0.62 nm, corresponding to interplanar spacing of 2H-MoS₂ (002) plane based on XRD results. The high magnification HR-TEM image of the thin MoS₂ layers (Fig. 4e) confirms that the as-prepared MoS₂ is typically hexagonal MoS₂. The interlayer distance of (100) plane and (110) plane are 0.27 and 0.16 nm, respectively. The selected area electron diffraction (SAED) (Fig. 4f) shows a clear monocrystalline MoS₂ diffraction pattern with six inner diffraction spots indicating (100) plane and the outer diffraction spots indicating (110) plane. There is no (002) plane diffraction spots because the electrons incident direction is [001]. Based on above analysis, during the formation of MoS₂ particles, large amounts of monocrystalline MoS₂ layers in different orientations stacked to form nanosheets, the multilayer nanosheets

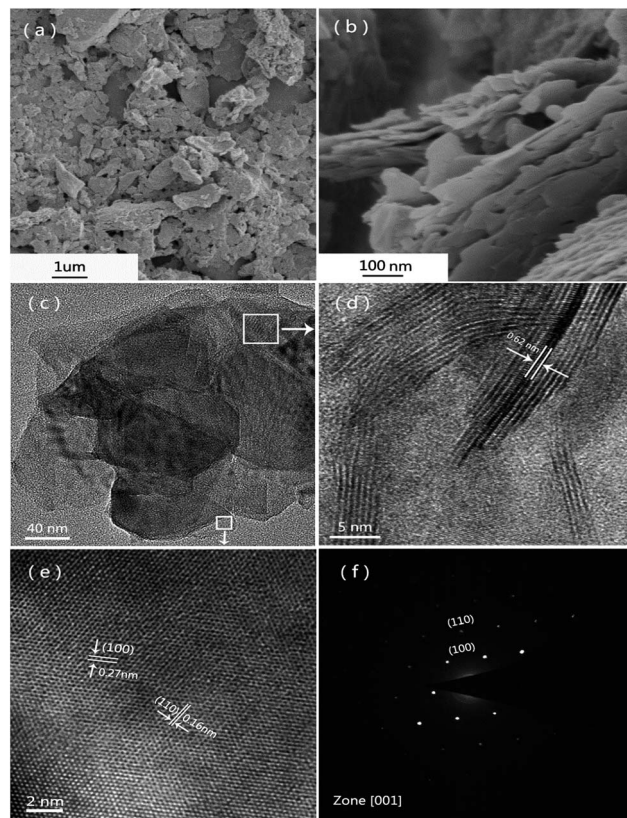


Fig. 4 SEM and TEM photos of as-prepared sample MoS₂-2.



arranged to form MoS₂ flakes, and then the flakes aggregated to construct crystalline MoS₂ particles.

We used the sample MoS₂-2 as the negative electrode of lithium ion battery because of its superior structure and composition. Fig. 5 depicts the cyclic voltammetry (CV) profile of as-prepared sample MoS₂-2. Cyclic voltammetry is a normal method to research the redox reactions of the electrodes. From Fig. 5, two obvious reduction peaks at 0.6 V and 0.4 V are shown in the first cycle. The peak at 0.6 V implies intercalation of lithium ions into MoS₂ layers with MoS₂ structure transformation from 2H (trigonal prismatic coordination) to the 1T (octahedral coordination).^{21–23} The other peak at 0.4 V can be attributed to the conversion reaction process of Li_xMoS₂ into Mo and Li₂S. In the anodic sweep, the peak in 2.25 V is attributed to the delithiation of Li₂S with the reaction process of Li₂S – 2e → 2Li⁺ + S.^{7,24,25} In the second and third cathodic sweep, three reduction peaks are found at 1.7 V, 1.0 V, and 0.2 V, respectively, which could be due to the following reactions: 2Li⁺ + S + 2e → Li₂S, MoS₂ + xLi⁺ + xe → Li_xMoS₂, and Li_xMoS₂ + (4 – x)Li⁺ + (4 – x)e → Mo + 2Li₂S.^{26,27}

Fig. 6 shows the first three charge–discharge profiles of the sample MoS₂-2 electrodes with a cutoff voltage of 0.005–3 V at a current density of 100 mA g^{–1}, which are nearly accord with the CV measurements described above. In the first discharge process, there are two obvious voltage plateaus at 0.5 V and 1.0 V, which indicates the formation of Li_xMoS₂ and the following conversion reaction of Li_xMoS₂ into Mo and Li₂S.^{1,17,28} The slope region below 0.5 V could be attributed to the formation of a solid-electrolyte interphase (SEI) layer.^{29,30} In the second and third discharge process, three vague potential plateaus could be found at 1.7 V, 1.0 V and 0.25 V, which are in qualitative agreement with the CV results. In the charge process, the MoS₂-2 electrode shows a distinct potential plateau at 2.25 V, which could be due to the reduction of sulfur to polysulfide.^{24,31,32} Fig. 6 also shows that the MoS₂-2 electrode delivers an initial discharge capacity of 1149 mA h g^{–1} and a reversible charge capacity of 1038 mA h g^{–1}, with a high coulombic efficiency of 90.3%.

Fig. 7a depicts the cycling behavior and rate capability of the sample MoS₂-2 at a constant current density of 100 mA g^{–1}. Although the first charge and discharge capacities are higher

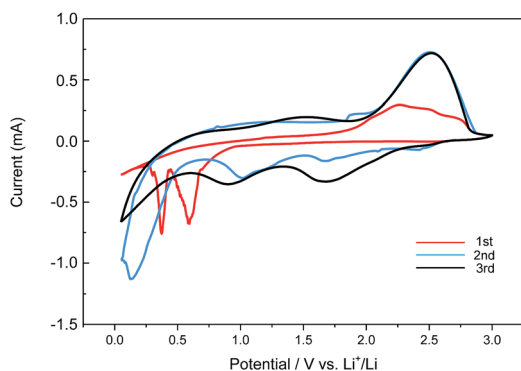


Fig. 5 The first three cyclic voltammograms of as-prepared sample MoS₂-2.

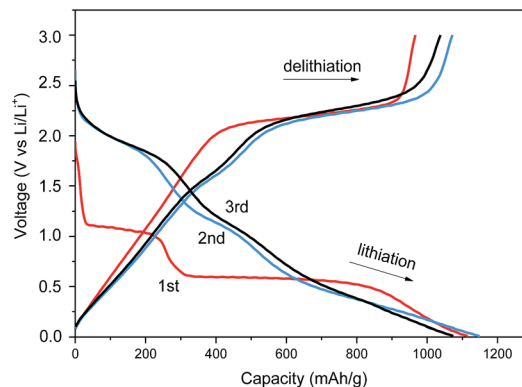


Fig. 6 Galvanostatic charge and discharge curves of as-prepared sample MoS₂-2 at a current density of 100 mA g^{–1}.

than 900 mA h g^{–1}, the cycling stability of the MoS₂-2 electrode is poor with a discharge capacity decrease from 947 to 353 mA h g^{–1} after 40 cycles. Fig. 7b shows the rate cycling behavior of the sample MoS₂-2 electrode. At the current densities of 1.0 A g^{–1}, the capacity rapidly declines below 300 mA h g^{–1}, which cannot compete with the MoS₂/graphene composite electrode with good rate performance. Surprisingly, the sample MoS₂-2 electrode has a high coulombic efficiency of nearly 100%.

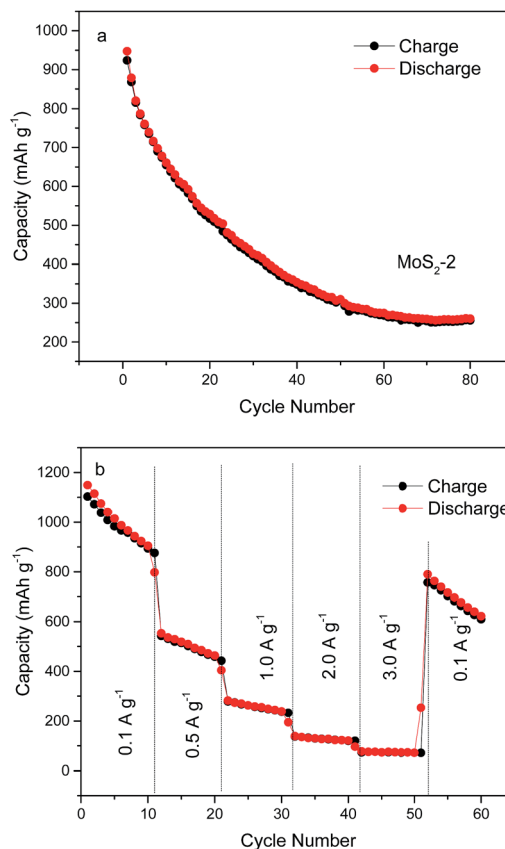


Fig. 7 (a) Cycle performance of as-prepared sample MoS₂-2 electrode at a current density of 0.1 A g^{–1}, and (b) their rate capabilities at different current densities.



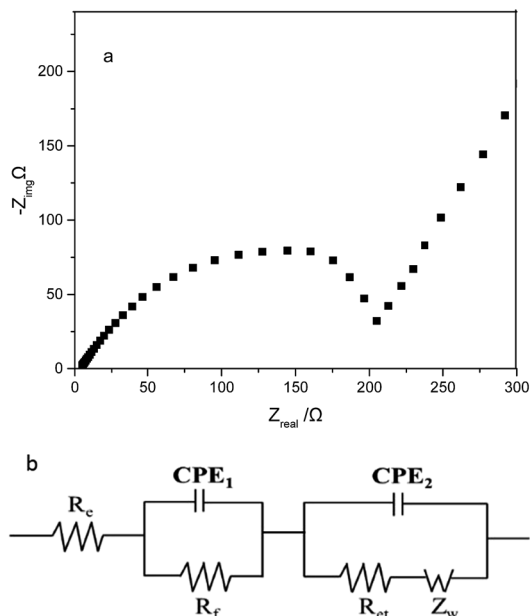


Fig. 8 (a) Nyquist plots of as-prepared sample MoS₂-2 electrode in the frequency range from 200 kHz to 0.01 Hz; and (b) an equivalent circuit model of the electrode, CPE is the constant phase element, $Z_{\text{CPE}} = \{Q(j\omega)^n\}^{-1}$, $0 < n < 1$.

Electrochemical impedance spectra (EIS) can be applied to better understand the electrochemical performance of MoS₂ electrode. Fig. 8a depicts the Nyquist plots of MoS₂-2 electrode after 40th cycle, and Fig. 8b is the equivalent circuit model for the impedance response. The semicircle in high-frequency region is due to the resistance R_f and CPE₁ of the solid electrolyte interphase (SEI) film.^{33,34} The medium-frequency semicircle corresponds to the charge-transfer resistance R_{ct} and CPE₂ of the electrode/electrolyte interface.^{35,36} The inclined line is assigned to the lithium-diffusion within the electrode material.³⁷ According to EIS equivalent circuit in Fig. 8b, R_f and R_{ct} of MoS₂-2 electrode are 14.84 and 121.9 Ω, respectively.

4. Conclusions

In summary, the multilayer MoS₂ crystal was synthesized by a chelation-assisted sol-gel method followed by calcination. Diethylenetriamine pentaacetic acid (Dtpa) as chelation agent was introduced to react with Mo and S sources to form Mo-S chelated gel. The mass ratio of Mo and S affected the formation of multilayer MoS₂ as well as the inner structure of MoS₂, and the best crystalline MoS₂ particles are obtained with the Mo and S mass ratio of 1 : 3. The resultant crystalline MoS₂ particles were constructed by irregular MoS₂ flakes arranged together, while these flakes were formed by adjustable MoS₂ layers stacked together. The electrochemical tests showed the possibility of as-prepared MoS₂ applied as negative electrode for lithium ion batteries. In order to improve the electrochemical performance, we need to continually explore a sol-gel process to prepare MoS₂/graphene composite with the aid of synergy effect

between MoS₂ and graphene and the superior electron conductivity of graphene.

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